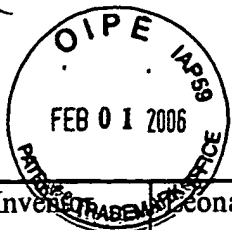


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First Named Inventor	Leonard Forbes	REPLY UNDER 37 C.F.R. §1.116 – EXPEDITED PROCEDURE – TECHNOLOGY CENTER 2800
Serial No.	10/808,059	
Filing Date	March 24, 2004	
Group Art Unit	2814	
Examiner Name	Marcos D. Pizarro Crespo	
Confirmation No.	4221	
Attorney Docket No.	400.285US01	
Title: NROM MEMORY DEVICE WITH HIGH-PERMITTIVITY GATE DIELECTRIC FORMED BY THE LOW TEMPERATURE OXIDIZATION OF METALS		

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Commissioner for Patents
P.O. Box 1450
Alexandria, VA 22313-1450

In response to the Final Office Action mailed December 13, 2005, please consider the following: